Contents L6384E

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L6384E Block diagram

# 1 Block diagram

H.V.  $V_{CC}$  $V_{\mathsf{BOOT}}$ BOOTSTRAP DRIVER HVG DRIVER C<sub>BOOT</sub> UV DETECTION HVG S OUT LOGIC IN O LOAD 6 LEVEL SHIFTER LVG DEAD LVG DT/SD GND DRIVER Vthi D97IN518A

Figure 1. Block diagram

Electrical data L6384E

### 2 Electrical data

### 2.1 Absolute maximum ratings

Table 1. Absolute maximum ratings

| Symbol                | Parameter  | Value                        | Unit |
|-----------------------|--|------------------------------|------|
| V <sub>OUT</sub>      | Output voltage                                   | -3 to V <sub>BOOT</sub> -18  | V    |
| V <sub>CC</sub>       | Supply voltage <sup>(1)</sup>                    | - 0.3 to 14.6                | V    |
| Is                    | Supply current <sup>(1)</sup>                    | 25                           | mA   |
| V <sub>BOOT</sub>     | Floating supply voltage                          | -1 to 618                    | V    |
| V <sub>hvg</sub>      | High-side gate output voltage                    | -1 to V <sub>BOOT</sub>      | V    |
| V <sub>Ivg</sub>      | Low-side gate output voltage                     | -0.3 to V <sub>CC</sub> +0.3 | V    |
| V <sub>i</sub>        | Logic input voltage                              | -0.3 to V <sub>CC</sub> +0.3 | V    |
| V <sub>SD</sub>       | Shutdown/deadtime voltage                        | -0.3 to V <sub>CC</sub> +0.3 | V    |
| dV <sub>out</sub> /dt | Allowed output slew rate                         | 50                           | V/ns |
| P <sub>tot</sub>      | Total power dissipation (T <sub>j</sub> = 85 °C) | 750                          | mW   |
| T <sub>J</sub>        | Junction temperature                             | 150                          | °C   |
| T <sub>s</sub>        | Storage temperature                              | -50 to 150                   | °C   |
| ESD                   | Human body model                                 | 2                            | kV   |

<sup>1.</sup> The device has an internal clamping Zener between GND and the  $V_{CC}$  pin, it must not be supplied by a low impedance voltage source.

#### 2.2 Thermal data

Table 2. Thermal data

| Symbol              | Parameter                              | SO-8 | DIP-8 | Unit |
|---------------------|--|------|-------|------|
| R <sub>th(JA)</sub> | Thermal resistance junction to ambient | 150  | 100   | °C/W |

L6384E Electrical data

## 2.3 Recommended operating conditions

Table 3. Recommended operating conditions

| Symbol                         | Pin | Parameter               | Test condition                      | Min. | Тур. | Max.        | Unit |
|--------------------------------|-----|-------------------------|-------------------------------------|------|------|-------------|------|
| V <sub>OUT</sub>               | 6   | Output voltage          |                                     | (1)  |      | 580         | V    |
| V <sub>BS</sub> <sup>(2)</sup> | 8   | Floating supply voltage |                                     | (1)  |      | 17          | V    |
| f <sub>sw</sub>                |     | Switching frequency     | HVG, LVG load C <sub>L</sub> = 1 nF |      |      | 400         | kHz  |
| V <sub>CC</sub>                | 2   | Supply voltage          |                                     |      |      | $V_{clamp}$ | V    |
| T <sub>j</sub>                 |     | Junction temperature    |                                     | -45  |      | 125         | °C   |

<sup>1.</sup> If the condition  $V_{BOOT}$  -  $V_{OUT}$  < 18 V is guaranteed,  $V_{OUT}$  can range from -3 to 580 V.



<sup>2.</sup>  $V_{BS} = V_{BOOT} - V_{OUT}$ 

Pin connection L6384E

## 3 Pin connection

Figure 2. Pin connection (top view)

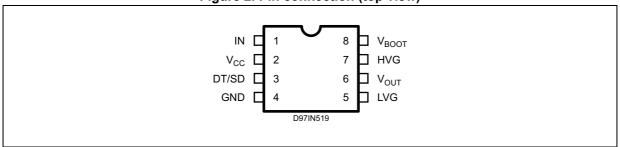


Table 4. Pin description

| No. | Pin               | Туре | Function   |
|-----|-------------------|------|--|
| 1   | IN                | I    | Logic input: it is in phase with HVG and in opposition of phase with LVG. It is compatible to $V_{CC}$ voltage. ( $V_{ilMax}$ = 1.5 V, $V_{ihMin}$ = 3.6 V).   |
| 2   | V <sub>CC</sub>   | Р    | Supply input voltage: there is an internal clamp [typ. 15.6 V].  |
| 3   | DT/SD             | ı    | High impedance pin with two functionalities. When pulled lower than $V_{dt}$ (typ. 0.5 V), the device is shut down. A voltage higher than $V_{dt}$ sets the deadtime between the high-side gate driver and low-side gate driver. The deadtime value can be set forcing a certain voltage level on the pin or connecting a resistor between the pin 3 and ground. Care must be taken to avoid below threshold spikes on the pin 3 that can cause undesired shutdown of the IC. For this reason the connection of the components between the pin 3 and ground has to be as short as possible. This pin can not be left floating for the same reason. The pin has not be pulled through a low impedance to $V_{CC}$ , because of the drop on the current source that feeds $R_{dt}$ . The operative range is: $V_{dt} \dots 270~K\Omega \cdot I_{dt}$ , that allows a dt range of 0.4 - 3.1 $\mu s$ . |
| 4   | GND               | Р    | Ground   |
| 5   | LVG               | 0    | Low-side driver output: the output stage can deliver 400 mA source and 650 mA sink (typ. values). The circuit guarantees 0.3 V max. on the pin (at $I_{sink}$ = 10 mA) with $V_{CC}$ > 3 V and lower than the turn-on threshold. This allows to omit the bleeder resistor connected between the gate and the source of the external MOSFET normally used to hold the pin low; the gate driver ensures low impedance also in SD conditions.   |
| 6   | V <sub>OUT</sub>  | Р    | High-side driver floating reference: layout care has to be taken to avoid below ground spikes on this pin.   |
| 7   | HVG               | 0    | High-side driver output: the output stage can deliver 400 mA source and 650 mA sink (typ. values). The circuit guarantees 0.3 V max. between this pin and $V_{OUT}$ (at $I_{sink}$ = 10 mA) with $V_{CC}$ > 3 V and lower than the turn-on threshold. This allows to omit the bleeder resistor connected between the gate and the source of the external MOSFET normally used to hold the pin low; the gate driver ensures low impedance also in SD conditions.  |
| 8   | V <sub>BOOT</sub> | Р    | Bootstrap supply voltage: it is the high-side driver floating supply. The bootstrap capacitor connected between this pin and the pin 6 can be fed by an internal structure named "bootstrap driver" (a patented structure). This structure can replace the external bootstrap diode.   |

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### 4 Electrical characteristics

### 4.1 AC operation

Table 5. AC operation electrical characteristics ( $V_{CC}$  = 14.4 V;  $T_J$  = 25 °C)

| Symbol            | Pin        | Parameter                                       | Test condition                       | Min. | Тур.       | Max. | Unit |
|-------------------|------------|---|--------------------------------------|------|------------|------|------|
| t <sub>on</sub>   | 1 vs. 5, 7 | High/low-side driver turn-on propagation delay  | $V_{OUT} = 0 V R_{dt} = 47 k\Omega$  |      | 200+<br>dt |      | ns   |
| t <sub>onsd</sub> | 3 vs. 5, 7 | Shutdown input propagation delay                |                                      |      | 220        | 280  | ns   |
|                   |            |   | $V_{OUT} = 0 V R_{dt} = 47 k\Omega$  |      | 250        | 300  | ns   |
| t <sub>off</sub>  | 1 vs. 5, 7 | High/low-side driver turn-off propagation delay | $V_{OUT} = 0 V R_{dt} = 146 k\Omega$ |      | 200        | 250  | ns   |
|                   |            | ,   | $V_{OUT} = 0 V R_{dt} = 270 k\Omega$ |      | 170        | 200  | ns   |
| t <sub>r</sub>    | 5, 7       | Rise time                                       | C <sub>L</sub> = 1000 pF             |      | 50         |      | ns   |
| t <sub>f</sub>    | 5, 7       | Fall time                                       | C <sub>L</sub> = 1000 pF             |      | 30         |      | ns   |

### 4.2 DC operation

Table 6. DC operation electrical characteristics  $(V_{CC}$  = 14.4 V;  $T_J$  = 25 °C)

| Symbol             | Pin                    | Parameter                                     | Test condition                                 | Min. | Тур. | Max. | Unit |  |  |
|--------------------|------------------------|---|--|------|------|------|------|--|--|
| Supply v           | Supply voltage section |   |  |      |      |      |      |  |  |
| V <sub>clamp</sub> | 2                      | Supply voltage clamping                       | I <sub>s</sub> = 5 mA                          | 14.6 | 15.6 | 16.6 | V    |  |  |
| V <sub>CCth1</sub> | 2                      | V <sub>CC</sub> UV turn-on threshold          |  | 11.5 | 12   | 12.5 | V    |  |  |
| V <sub>CCth2</sub> |                        | V <sub>CC</sub> UV turn-off threshold         |  | 9.5  | 10   | 10.5 | V    |  |  |
| V <sub>CChys</sub> |                        | V <sub>CC</sub> UV hysteresis                 |  |      | 2    |      | V    |  |  |
| I <sub>QCCU</sub>  | 2                      | Undervoltage quiescent supply current         | V <sub>CC</sub> ≤ 11 V                         |      | 150  |      | μА   |  |  |
| I <sub>QCC</sub>   |                        | Quiescent current                             | V <sub>IN</sub> = 0                            |      | 380  | 500  | μА   |  |  |
| Bootstra           | pped supply            | voltage section                               |  |      |      |      |      |  |  |
| V <sub>BOOT</sub>  |                        | Bootstrap supply voltage                      |  |      |      | 17   | V    |  |  |
| I <sub>QBS</sub>   | 8                      | Quiescent current                             | IN = HIGH                                      |      |      | 100  | μА   |  |  |
| I <sub>LK</sub>    | 0                      | High voltage leakage current                  | $V_{hvg} = V_{OUT} = V_{BOOT} = 600 \text{ V}$ |      |      | 10   | μА   |  |  |
| R <sub>dson</sub>  |                        | Bootstrap driver on-resistance <sup>(1)</sup> | V <sub>CC</sub> ≥ 12.5 V; IN = LOW             |      | 125  |      | Ω    |  |  |
| High/low           | High/low-side driver   |   |  |      |      |      |      |  |  |
| I <sub>so</sub>    | 5, 7                   | Source short-circuit current                  | $V_{IN} = V_{ih} (t_p < 10 \ \mu s)$           | 300  | 400  |      | mA   |  |  |
| I <sub>si</sub>    | 5, 7                   | Sink short-circuit current                    | $V_{IN} = V_{il} (t_p < 10 \ \mu s)$           | 500  | 650  |      | mA   |  |  |



Electrical characteristics L6384E

| Symbol           | Pin        | Parameter                             | Test condition  | Min. | Тур.              | Max. | Unit           |
|------------------|------------|---------------------------------------|---|------|-------------------|------|----------------|
| Logic inp        | outs       |                                       |   |      |                   |      |                |
| V <sub>il</sub>  |            | Low level logic threshold voltage     |   |      |                   | 1.5  | V              |
| V <sub>ih</sub>  | 1, 3       | High level logic threshold voltage    |   | 3.6  |                   |      | V              |
| I <sub>ih</sub>  |            | High level logic input current        | V <sub>IN</sub> = 15 V  |      | 50                | 70   | μА             |
| I <sub>il</sub>  |            | Low level logic input current         | V <sub>IN</sub> = 0 V   |      |                   | 1    | μА             |
| I <sub>ref</sub> | 3          | Deadtime setting current              |   |      | 28                |      | μА             |
| dt               | 3 vs. 5, 7 | Deadtime setting range <sup>(2)</sup> | $R_{dt} = 47 \text{ k}\Omega$<br>$R_{dt} = 146 \text{ k}\Omega$<br>$R_{dt} = 270 \text{ k}\Omega$ | 0.4  | 0.5<br>1.5<br>2.7 | 3.1  | μs<br>μs<br>μs |
| V <sub>dt</sub>  | 3          | Shutdown threshold                    |   |      | 0.5               |      | V              |

Table 6. DC operation electrical characteristics (continued) ( $V_{CC}$  = 14.4 V;  $T_J$  = 25 °C)

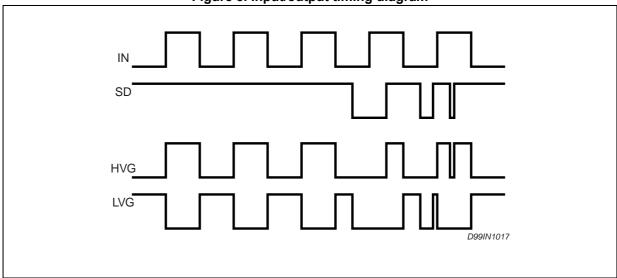
$$R_{DSON} = \frac{(V_{CC} - V_{BOOT1}) - (V_{CC} - V_{BOOT2})}{I_1(V_{CC}, V_{BOOT1}) - I_2(V_{CC}, V_{BOOT2})}$$

Where  $I_1$  is the pin 8 current when  $V_{BOOT} = V_{BOOT1}$ ,  $I_2$  when  $V_{BOOT} = V_{BOOT2}$ .

2. The pin 3 is a high impedance pin. Therefore dt can be set also forcing a certain voltage  $V_3$  on this pin. The deadtime is the same obtained with an  $R_{dt}$  if it is:  $R_{dt} \times I_{ref} = V_3$ .

### 4.3 Timing diagram

Figure 3. Input/output timing diagram



<sup>1.</sup>  $R_{DS(on)}$  is tested in the following way:

L6384E Bootstrap driver

### 5 Bootstrap driver

A bootstrap circuitry is needed to supply the high voltage section. This function is normally accomplished by a high voltage fast recovery diode (*Figure 4* a). In the L6384E device a patented integrated structure replaces the external diode. It is realized by a high voltage DMOS, driven synchronously with the low-side driver (LVG), with a diode in series, as shown in *Figure 4* b. An internal charge pump (*Figure 4* b) provides the DMOS driving voltage. The diode connected in series to the DMOS has been added to avoid undesirable turn-on.

### **C**BOOT selection and charging

To choose the proper  $C_{BOOT}$  value the external MOSFET can be seen as an equivalent capacitor. This capacitor  $C_{EXT}$  is related to the MOSFET total gate charge:

#### **Equation 1**

$$C_{EXT} = \frac{Q_{gate}}{V_{gate}}$$

The ratio between the capacitors  $C_{\text{EXT}}$  and  $C_{\text{BOOT}}$  is proportional to the cyclical voltage loss. It has to be:

E.g.: if  $Q_{gate}$  is 30 nC and  $V_{gate}$  is 10 V,  $C_{EXT}$  is 3 nF. With  $C_{BOOT}$  = 100 nF the drop would be 300 mV.

If HVG has to be supplied for a long time, the  $C_{BOOT}$  selection has to take into account also the leakage losses.

E.g.: HVG steady state consumption is lower than 100  $\mu$ A, so if HVG T<sub>ON</sub> is 5 ms, C<sub>BOOT</sub> has to supply 0.5  $\mu$ C to C<sub>EXT</sub>. This charge on a 1  $\mu$ F capacitor means a voltage drop of 0.5 V.

The internal bootstrap driver gives great advantages: the external fast recovery diode can be avoided (it usually has a great leakage current).

This structure can work only if  $V_{OUT}$  is close to GND (or lower) and in the meanwhile the LVG is on. The charging time ( $T_{charge}$ ) of the  $C_{BOOT}$  is the time in which both conditions are fulfilled and it has to be long enough to charge the capacitor.

The bootstrap driver introduces a voltage drop due to the DMOS  $R_{DSON}$  (typical value: 125  $\Omega$ ). At low frequency this drop can be neglected. Anyway increasing the frequency it must be taken in to account.

The following equation is useful to compute the drop on the bootstrap DMOS:

#### **Equation 2**

$$V_{drop} = I_{charge}R_{dson} \rightarrow V_{drop} = \frac{Q_{gate}}{T_{charge}}R_{dson}$$

where  $Q_{gate}$  is the gate charge of the external power MOSFET,  $R_{dson}$  is the on-resistance of the bootstrap DMOS, and  $T_{charge}$  is the charging time of the bootstrap capacitor.



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Bootstrap driver L6384E

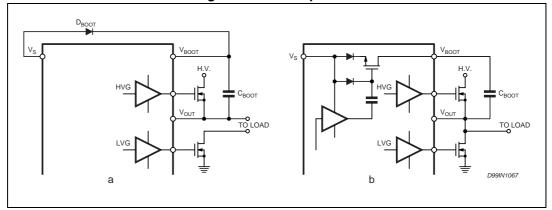
For example: using a power MOSFET with a total gate charge of 30 nC, the drop on the bootstrap DMOS is about 1 V, if the  $T_{charge}$  is 5  $\mu s$ . In fact:

#### **Equation 3**

$$V_{drop} = \frac{30nC}{5\mu s} \cdot 125\Omega \sim 0.8V$$

 $V_{drop}$  has to be taken into account when the voltage drop on  $C_{BOOT}$  is calculated: if this drop is too high, or the circuit topology doesn't allow a sufficient charging time, an external diode can be used.

Figure 4. Bootstrap driver



## 6 Typical characteristic

Figure 5. Typical rise and fall times vs. load capacitance

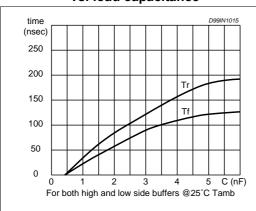


Figure 6. Quiescent current vs. supply voltage

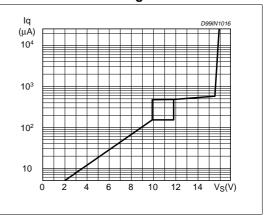


Figure 7. Deadtime vs. resistance

3.5 3.0 ② Vcc = 14.4V 2.5 1.0 0.5 0.0 50 100 150 200 250 300 Rdt (kΩ)

Figure 8. Driver propagation delay vs. temperature

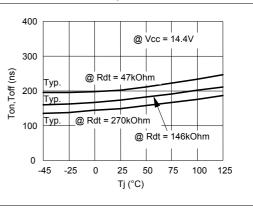


Figure 9. Deadtime vs. temperature

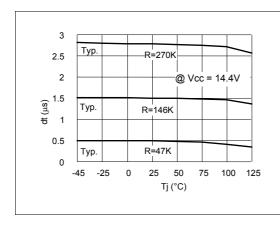
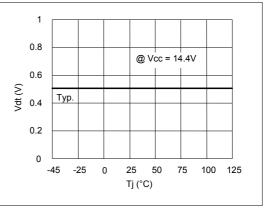


Figure 10. Shutdown threshold vs. temperature

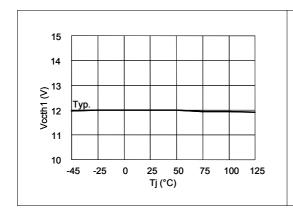


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Typical characteristic L6384E

Figure 11.  $V_{CC}$  UV turn-on vs. temperature

Figure 12. Output source current vs. temperature



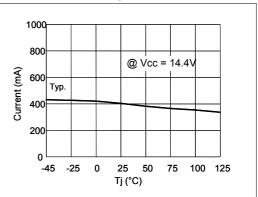
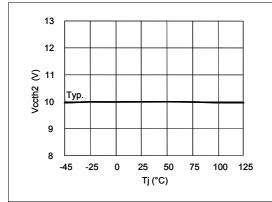
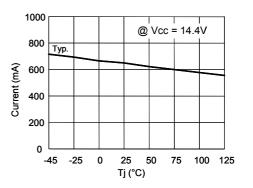


Figure 13. V<sub>CC</sub> UV turn-off vs. temperature

Figure 14. Output sink current vs. temperature





L6384E Package information

## 7 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: <a href="www.st.com">www.st.com</a>. ECOPACK is an ST trademark.

### 7.1 DIP-8 package information

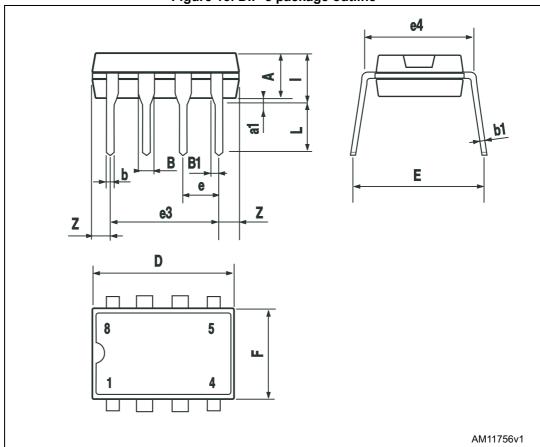


Figure 15. DIP-8 package outline

Package information L6384E

Table 7. DIP-8 package mechanical data

| Symbol | Dimensions (mm) |      |       | Dimensions (inch) |       |       |
|--------|-----------------|------|-------|-------------------|-------|-------|
|        | Min.            | Тур. | Max.  | Min.              | Тур.  | Max.  |
| Α      |                 | 3.32 |       |                   | 0.131 |       |
| a1     | 0.51            |      |       | 0.020             |       |       |
| В      | 1.15            |      | 1.65  | 0.045             |       | 0.065 |
| b      | 0.356           |      | 0.55  | 0.014             |       | 0.022 |
| b1     | 0.204           |      | 0.304 | 0.008             |       | 0.012 |
| D      |                 |      | 10.92 |                   |       | 0.430 |
| E      | 7.95            |      | 9.75  | 0.313             |       | 0.384 |
| е      |                 | 2.54 |       |                   | 0.100 |       |
| e3     |                 | 7.62 |       |                   | 0.300 |       |
| e4     |                 | 7.62 |       |                   | 0.300 |       |
| F      |                 |      | 6.6   |                   |       | 0.260 |
| I      |                 |      | 5.08  |                   |       | 0.200 |
| L      | 3.18            |      | 3.81  | 0.125             |       | 0.150 |
| Z      |                 |      | 1.52  |                   |       | 0.060 |

L6384E Package information

# 7.2 SO-8 package information

D hx45'

Nx45'

SEATING PLANE

C GAGE PLANE

AM11757V1

Figure 16. SO-8 package outline

Package information L6384E

Table 8. SO-8 package mechanical data

| Comple el         | Dimensions (mm) |       |       | Dimensions (inch) |        |        |
|-------------------|-----------------|-------|-------|-------------------|--------|--------|
| Symbol            | Min.            | Тур.  | Max.  | Min.              | Тур.   | Max.   |
| Α                 |                 |       | 1.750 |                   |        | 0.0689 |
| A1                | 0.100           |       | 0.250 | 0.0039            |        | 0.0098 |
| A2                | 1.250           |       |       | 0.0492            |        |        |
| b                 | 0.280           |       | 0.480 | 0.0110            |        | 0.0189 |
| С                 | 0.170           |       | 0.230 | 0.0067            |        | 0.0091 |
| D <sup>(1)</sup>  | 4.800           | 4.900 | 5.000 | 0.1890            | 0.1929 | 0.1969 |
| E                 | 5.800           | 6.000 | 6.200 | 0.2283            | 0.2362 | 0.2441 |
| E1 <sup>(2)</sup> | 3.800           | 3.900 | 4.000 | 0.1496            | 0.1535 | 0.1575 |
| е                 |                 | 1.270 |       |                   | 0.0500 |        |
| h                 | 0.250           |       | 0.500 | 0.0098            |        | 0.0197 |
| L                 | 0.400           |       | 1.270 | 0.0157            |        | 0.0500 |
| L1                |                 | 1.040 |       |                   | 0.0409 |        |
| k                 | 0°              |       | 8°    | 0°                |        | 8°     |
| ccc               |                 |       | 0.100 |                   |        | 0.0039 |

Dimension "D" does not include mold flash, protrusions or gate burrs. Mold flash, protrusions or gate burrs shall not exceed 0.15 mm in total (both sides).

Dimension "E1" does not include interlead flash or protrusions. Interlead flash or protrusions shall not exceed 0.25 mm per side.

L6384E Order codes

### 8 Order codes

Table 9. Order code

| Order code   | Package | Packaging     |
|--------------|---------|---------------|
| L6384E       | DIP-8   | Tube          |
| L6384ED      | SO-8    | Tube          |
| L6384ED013TR | SO-8    | Tape and reel |

## 9 Revision history

**Table 10. Document revision history** 

| Date        | Revision | Changes   |
|-------------|----------|---|
| 12-Oct-2007 | 1        | First release   |
| 20-Jun-2014 | 2        | Added Section: Applications on page 1.  Updated Section: Description on page 1 (replaced by new description).  Updated Table 1: Device summary on page 1 (moved from page 15 to page 1, updated title).  Updated Figure 1: Block diagram on page 3 (moved from page 1 to page 3, numbered and added title to Section 1: Block diagram on page 3).  Updated Section 2.1: Absolute maximum ratings on page 4 (removed note below Table 2: Absolute maximum ratings).  Updated Table 5: Pin description on page 5 (updated "Type" of several pins).  Updated Table 7 on page 6 (updated "Max." value of IQBS symbol).  Updated Section: CBOOT selection and charging on page 8 (updated values of "E.g.: HVG").  Numbered Equation 1 on page 8, Equation 2 on page 8 and Equation 3 on page 9.  Updated Section 7: Package information on page 12 [updated/added titles, updated ECOPACK text, reversed order of Figure 15 and Table 8, Figure 16 and Table 9 (numbered tables), removed 3D package figures, minor modifications].  Minor modifications throughout document. |
| 16-Sep-2015 | 3        | Updated <i>Table 1 on page 4</i> (added ESD parameter and value, minor modifications). Updated note <i>1.</i> below <i>Table 6 on page 7</i> (replaced V <sub>CBOOTx</sub> by V <sub>BOOTx</sub> ). Moved <i>Table 9 on page 17</i> (moved from page 1 to page 17, updated titles). Updated cross-references throughout document. Minor modifications throughout document.  |

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